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Silicon, Boron and Arsenic Derivatives of Phosphorus(Iv) Thioacids in Synthesis of Novel Organothiophosphorus Compounds

Il Yas S. Nizamov^a; Alexey E. Popovich^a; Gul'Nur G. Sergeenko^a; Alexey V. Matseevskii^a; Elvira S. Batyeva^a

^a A. E. Arbuzov Institute of Organic and Physical Chemistry, Kazan, RUSSIA

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Silicon, Boron and Arsenic Derivatives of Phosphorus(Iv) Thioacids in Synthesis of Novel Organothiophosphorus Compounds

IL'YAS S. NIZAMOV, ALEXEY E. POPOVICH, GUL'NUR G. SERGEENKO, ALEXEY V. MATSEEVSKII and ELVIRA S. BATYEVA

A. E. Arbuzov Institute of Organic and Physical Chemistry, Arbuzov str. 8, Kazan 420088, RUSSIA

We have found that S-boron O-alkyl(aryl)dithiophosphonates react with organic substances containing reactive multiple bonds such as methyl acrylate, vinyl butyl ether, vinyl acetate under mild conditions to form products of insertions into the S-B bond. The similar results were obtained in the case of S-arsenic O-alkyl(aryl)dithiophosphonates.

New types of seven and eight membered phosphacyclanes containing endocyclic fragment P-S-E (E = C, Si, Ge, Sn, P, As, Sb, Bi) were synthesized in the reactions of disilyl dithio- and trithiophosphonates with halides, alkoxides, phenoxides and mercaptides of main groups IV and V elements.

Since
$$S = EY_m$$
Ar-P
OSiMe $S = EY_m$
Ar-P
O
OSiMe $S = EY_m$
Ar-P
O
O
O

Ar = 4-MeOC₆H₄; E = C, Ge, Sn, P, As, Sb, Bi; X = Cl, Br, SR, OR;
Y = Cl, Br, Ph, SR, OR; R = Alk, Ph; n = 2, 3; m = 0, 1

Their spectral, structural and physical properties have been studied.